# **DSA7102**

# Silicon PNP epitaxial planar type

For low frequency output amplification Complementary to DSC7102 DSA8102 in MiniP3 type package

#### ■ Features

- Contributes to miniaturization of sets, reduction of component count.
- Eco-friendly Halogen-free package

#### ■ Packaging

Embossed type (Thermo-compression sealing): 1000 pcs / reel (standard)

### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	-80	V	
Collector-emitter voltage (Base open)	$V_{CEO}$	-80	V	
Emitter-base voltage (Collector open)	$V_{EBO}$	-5	V	
Collector current	$I_{C}$	-1	A	
Peak collector current	$I_{CP}$	-1.5	A	
Collector power dissipation *	P <sub>C</sub>	1	W	
Junction temperature	$T_j$	150	°C	
Storage temperature	T <sub>stg</sub>	-55 to +150	°C	

Note) \*: Printed circuit board: Copper foil area of 1 cm $^2$  or more, and the board thickness of 1.7 mm for the collector portion

Absolute maximum rating without heat sink for  $P_C$  is 0.5 W

#### ■ Package

- Code MiniP3-F2-B
- Pin Name
  - 1. Base
  - 2. Collector
  - 3. Emitter
- Marking Symbol: 4D

#### ■ Electrical Characteristics $T_a = 25$ °C±3°C

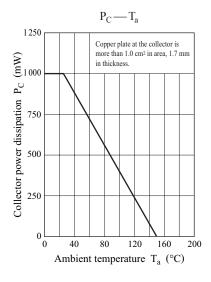
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	$V_{CBO}$	$I_{\rm C} = -10 \mu\text{A}, I_{\rm E} = 0$	-80			V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_C = -1 \text{ mA}, I_B = 0$	-80			V
Emitter-base voltage (Collector open)	$V_{EBO}$	$I_E = -10 \mu\text{A}, I_C = 0$	-5			V
Collector-base cutoff current (Emitter open)	I <sub>CBO</sub>	$V_{CB} = -40 \text{ V}, I_E = 0$			-0.1	μΑ
Forward current transfer ratio *1	h <sub>FE1</sub> *2	$V_{CE} = -2 \text{ V}, I_{C} = -100 \text{ mA}$	120		340	
	h <sub>FE2</sub>	$V_{CE} = -2 \text{ V}, I_{C} = -500 \text{ mA}$	60			_
Collector-emitter saturation voltage *1	V <sub>CE(sat)</sub>	$I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$		-0.2	-0.3	V
Base-emitter saturation voltage *1	V <sub>BE(sat)</sub>	$I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$		- 0.95	-1.2	V
Transition frequency	$f_T$	$V_{CE} = -10 \text{ V}, I_{C} = -50 \text{ mA}$		150		MHz
Collector output capacitance (Common base, input open circuited)	C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		12	30	pF

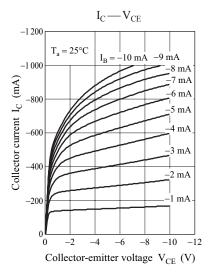
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

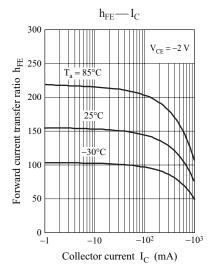
- 2. \*1: Pulse measurement
  - \*2: Rank classification

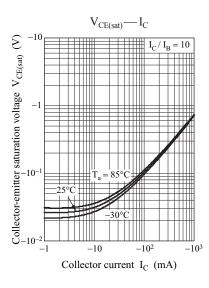
R	S
R	S
120 to 240	170 to 340
4DR	4DS

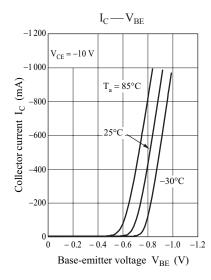
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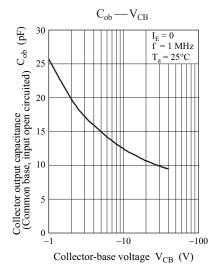


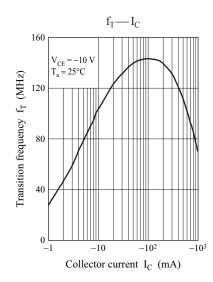








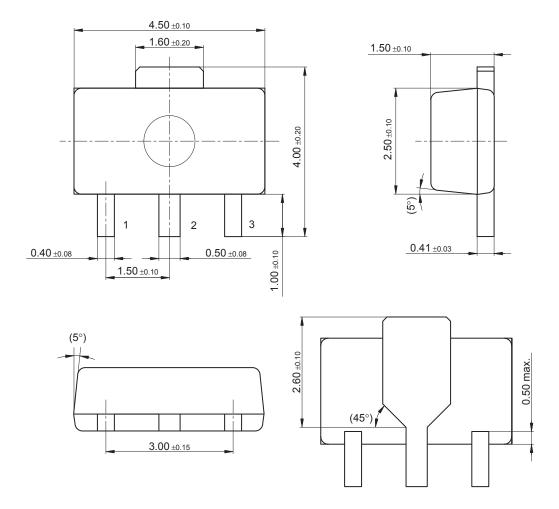




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MiniP3-F2-B

Unit: mm



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